Product data sheet

1. General description

Silicon Carbide Schottky diode in a TO220F-2L plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- New 6th Generation Technology
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Forward Surge Capability I_{FSM}
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- Insulated package rated at 2500V RMS

3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	s Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				650		V
l _F	continuous forward current	$T_h \le 63 ^{\circ}\text{C}, \text{DC}; \underline{\text{Fig. 2}}$			20		Α
T _j	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.26	1.40	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.35	1.55	V
Dynamic	characteristics				,		
Q _r	recovered charge	$I_F = 20 \text{ A}; dI_F/dt = 500 \text{ A/}\mu\text{s}; V_R = 400 \text{ V};$ $T_i = 25 ^{\circ}\text{C}; \text{ per diode}; \frac{\text{Fig. 7}}{1000}$		-	48	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 A
2	Α	anode		K — A 001aaa020
mb	n.c.	mounting base; isolated		
			0	
			1 2	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing guantity	Package version	Package issue date
WNSC6D20650X	TO220F-2L	WNSC6D20650X6Q	Tube	50	TO220FE-2L	21-Dec-2020

7. Marking

Table 4. Marking codes

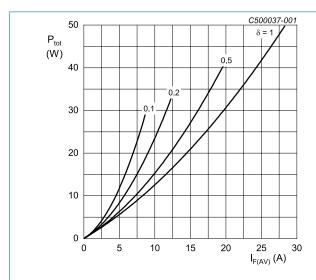
Type number	Marking codes
WNSC6D20650X	WNSC6D 20650X

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
l _F	continuous forward current	T _h ≤ 63 °C, DC; <u>Fig. 2</u>		20	А
		T _h ≤ 125 °C, DC; <u>Fig. 2</u>		10	А
		T _h ≤ 25 °C, DC; <u>Fig. 2</u>		24	А
I _{FRM}	repetitive peak forward current	$δ = 0.5$; $t_p = 25 \mu s$; $T_h \le 125 °C$; square-wave pulse		18	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		125	Α
	forward current	t _p = 10 μs; T _{j(init)} = 25 °C; square-wave pulse		1000	Α
l ² t	I ² t for fusing	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		78.125	A ² s
T _{stg}	storage temperature			-55 to 175	°C
T _j	junction temperature			-55 to 175	°C



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 0.984 \text{ V; } R_{\text{s}} = 0.0274 \text{ }\Omega \end{split}$$
 Fig. 1. Forward power dissipation as a function of average forward current; square waveform;

maximum values

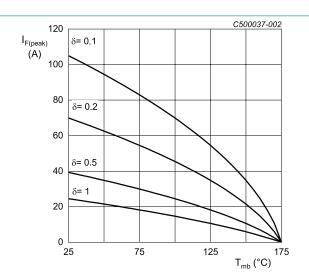
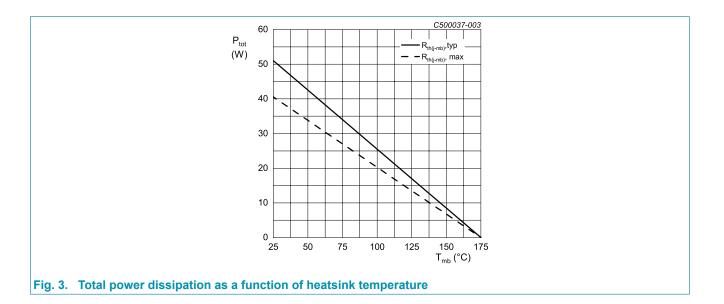


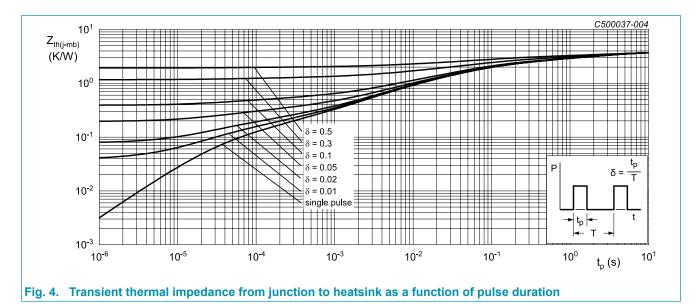
Fig. 2. Current derating as a function of heatsink temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to heatsink	with heatsink compound; Fig. 4		-	2.94	3.7	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W



10. Isolation characteristics

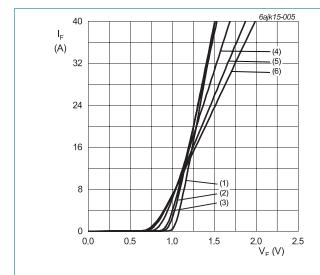
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; T _h = 25 °C; RH \leq 65 %		-	-	2500	V

11. Characteristics

Table 8. Characteristics

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Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
V_{F}	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.26	1.40	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.35	1.55	V
		I _F = 20 A; T _j = 175 °C; <u>Fig. 5</u>		-	1.40	1.60	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>		-	2	100	μΑ
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>		-	30	400	μΑ
Dynamic	characteristics						
Q_{r}	recovered charge	$I_F = 20 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 25 ^{\circ}\text{C}$; Fig. 7		-	48	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	1005	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C		-	110	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C		-	102	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 7.8 A; T _{j(init)} = 25 °C; L = 5 mH		150	-	-	mJ



 $V_0 = 0.984 \text{ V}; R_s = 0.0274 \Omega$

(1) T_i = -55 °C; typical values

(2) T_i = 0 °C; typical values

(3) T_i = 25 °C; typical values

(4) T_j = 100 °C; typical values (5) T_j = 150 °C; typical values (6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

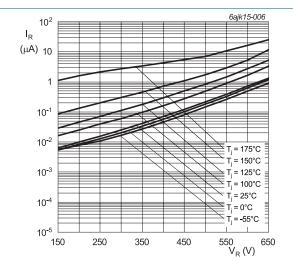
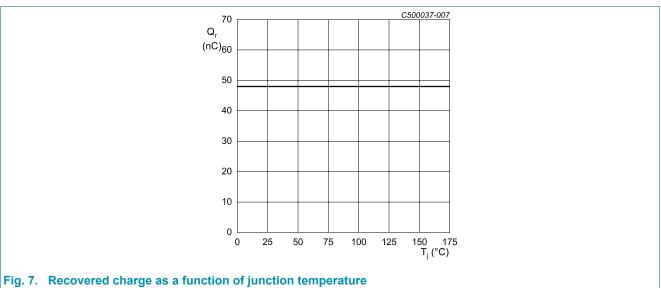
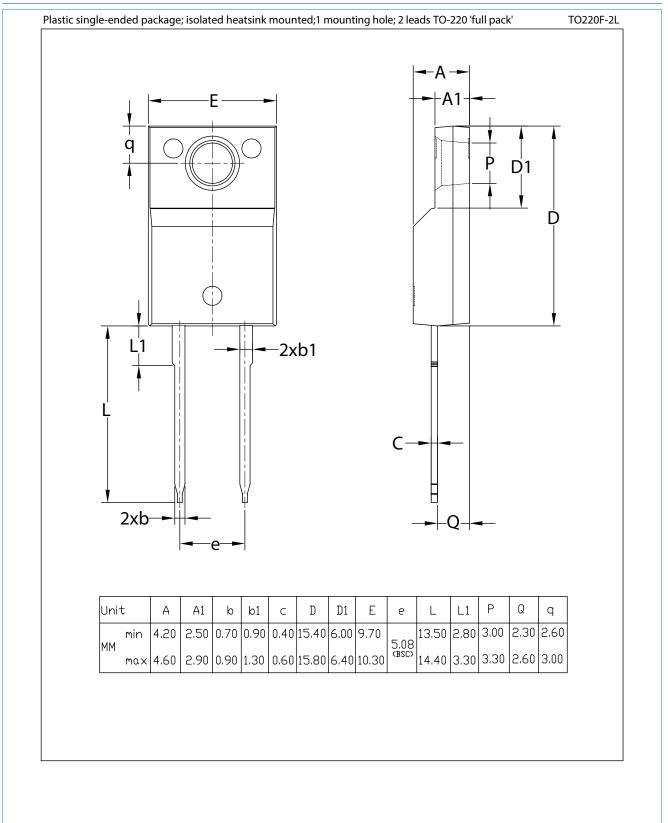


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



12. Package outline



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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14. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10). Isolation characteristics	5
11	. Characteristics	6
12	Package outline	8
	B. Legal information	
	. Contents	

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